NSN 5961-01-181-7424

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-181-7424 **Inclosure Material:** Plastic **Overall Length:** 0.285 inches **Overall Diameter:** 0.205 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method:** Unthreaded hole **Features Provided:** W/heat sink **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open and 50.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead and 1 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:**